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View Online at https://aerobasegroup.com/nsn/5961-01-243-1931 **Inclosure Material:** Metal **Overall Length:** Between 0.305 inches and 0.335 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 drain to gate voltage and 400.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 1.25 amperes drain current and 1.25 amperes source current and 5.50 amperes off-state current, peak **Power Rating Per Characteristic:** 15.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/556 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

Demilitarization: Yes - demil/mli

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Mil-std (military Standard):

Mil-prf-19500 spec.